## NSN 5962-01-310-8691

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Body Length:	
0.440 inches	
Body Width:	
0.285 inches	
Body Height:	
0.085 inches	
Maximum Power [	Dissipation Rating:
332.8 milliwatts	
Operating Tempur	ature Range:
-55.0/+125.0 degre	es celsius
Storage Tempurat	ure Range:
-65.0/+150.0 degre	es celsius
Features Provided	:
Monolithic and w/or	pen collector and bipolar and programmable
Inclosure Material	:
Ceramic	
Inclosure Configu	ration:
Flat pack	
Output Logic Forn	n:
Transistor-transisto	r logic
Input Circuit Patte	rn:
6 input	
Case Outline Sour	ce And Designator:
F-5 mil-m-38510	
Terminal Surface	Treatment:
Solder	
Voltage Rating An	d Type Per Characteristic:
7.0 volts power sou	urce
Time Rating Per C	hacteristic:
50.00 nanoseconds	propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	/pe:
Rom	
Test Data Docume	ent:
96906-mil-std-883 :	standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	d Quantity:
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

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